

BSC027N10NS5ATMA1

Data Sheet

OptiMOSTM best-in-class power MOSFETs in SuperSO8 package

Manufacturers

Infineon Technologies Corporation

Package/Case

PG-TSON-8

Product Type

RoHS

Lifecycle



Images are for reference only

Please submit RFQ for BSC027N10NS5ATMA1 or Email to us; sales@ovaga.com We will contact you in 12 hours.

RFO

General Description

Infineon's OptiMOSTM BiC MOSFETs in SuperSO8 package extend OptiMOSTM 3 and 5 product portfolio and enable higher power density in addition to improved robustness, responding to the need for lower system cost and increased performance.

Low reverse recovery charge (Q_{rr}) improves the system reliability by providing a significant reduction of voltage overshoot, which minimizes the need for snubber circuits, resulting in less engineering cost and effort.

Related Products



BSS192P

Infineon Technologies Corporation SOT89



BSP299

Infineon Technologies Corporation SOT-223



BSP129

Infineon Technologies Corporation SOT-223



BSP280

Infineon Technologies Corporation SOT223



BSP125

Infineon Technologies Corporation SOT-223



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